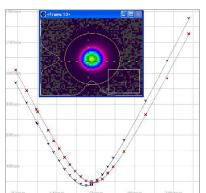


Mesa, the diode pumped Nd:YAG laser

Our Mesa Series of lasers is ideally suited for a broad range of scientific and industrial applications, including micromachining, where small kerf width and excellent edge quality are the most important process requirements. This series of lasers is optimized with astigmatism-free circular beams and superior stability to ensure the highest process quality. Our pumping technology and stable optical resonator design produce a laser beam with uniform energy distribution and high output power. The harmonic output at 532 nm is ideal for processing materials such as semiconductor wafers, solar cells, copper, polyamide, printed circuit boards, and plastics.

Scientific Applications

Ti:Sapphire pumping
Particle Image Velocimetry (PIV)
Combustion Analysis
Laser Induced Fluorescence
LIDAR
Resonance Raman Spectroscopy
Chemical Analysis of Macromolecules
Laser Microprobe Analysis



Industrial Applications

Stent/Glass/PCB/Fine Metal Cutting LCD/Solar Edge Deletion Marking Wafer Trimming Micro-hole Drilling Ceramics Scribing Fine Wire Stripping Diamond/Gemstone Processing

Diode Pumped Nd:YAG Diode Pumped Nd:YAG Diode Pumped Nd:YAG

1064 and 532 nm operation

Smooth and symmetrical beam profile

Highly efficient wavelength conversion

Consistent output over wide power range

Compact & rugged package designed for 24/7 operation

Record 3 min. diode module replacement with no realignment necessary

Proprietary optical cavity design for optimal beam quality





Mesa Specifications

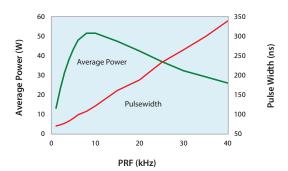
| Description | 1064- 100-M | 1064- 50-M | 1064- 25-M | 1064- 25-0 | 1064- 20-0-P | 532- 60-M | 532- 40-L | 532- 40-M | 532- 20-0 | 532- 16-0 | 532- 10-0 |
|--|----------------|---------------|---------------|---------------|-----------------|--------------|--------------|--------------|--------------|--------------|--------------|
| Wavelength | 1064 | 1064 | 1064 | 1064 | 1064 | 532 | 532 | 532 | 532 | 532 | 532 |
| Power CW (W) | 100 | 50 | 25 | 25 | 20 | n/a | n/a | n/a | n/a | n/a | n/a |
| Power at 10 kHz (W) | 75 | 37 | 18 | 20 | 14 | 60 | 40 | 40 | 20 | 16 | 10 |
| Power at 6 kHz (W) | 60 | 30 | 14 | 17 | 10 | 55 | 40 | 40 | 18 | 16 | 9 |
| Repetition Rate (kHz) | 1-40 | 1-40 | 1-40 | 1-40 | 1-40 | 1-30 | 1-30 | 1-30 | 1-30 | 1-30 | 1-30 |
| Pulse-to-Pulse Stability (% RMS) ¹ | <2 | <2 | <3 | <2 | <2 | <2 | <3 | <2 | <3 | <3 | <3 |
| Pulsewidth (ns) | <160 | <200 | <220 | <140 | <140 | <150 | <150 | <170 | <110 | <110 | <130 |
| Beam Pointing Stability (µrad RMS) | <20 | <30 | <30 | <15 | <15 | <20 | <20 | <20 | <15 | <15 | <15 |
| Beam Diameter (mm) ^{2, 3} | 6 | 6 | 6 | 1.1 | 1.0 | 3.5 | 2.2 | 4.0 | 0.9 | 0.9 | 8.0 |
| Beam Divergence (mrad) ² | 9.5 | 7 | 7 | 3 | 3 | 7 | 5 | 7 | 2.3 | 2.3 | 1.7 |
| Beam Quality (M²) | <20 | <12 | <12 | <1.2 | <1.2 | <25 | <12 | <25 | <1.2 | <1.2 | <1.2 |
| Polarization ⁴ | random | random | random | random | V 100:1 | V 100:1 | V 100:1 | V 100:1 | V 100:1 | V 100:1 | V 100:1 |

Notes

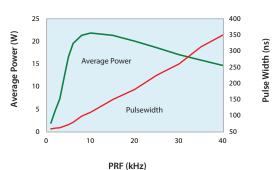
- 1. All specifications at 6 kHz unless otherwise noted
- 2. Typical measurement (±10%)
- 3. Measured at 13.5% level at output window
- 4. V=Vertical. Factory default (can be changed upon request)

As a part of our continuous improvement program, all specifications are subject to change without notice.

Laser System Output Characteristics



Laser System Output Characteristics Mesa 532-40-M



Laser System Output Characteristics Mesa 532-20-0

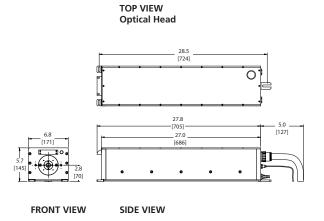


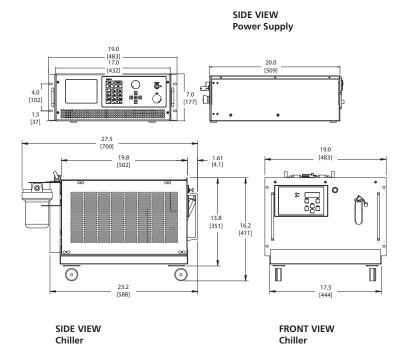
Mesa System Requirements

| Size | Optical Head (LxWxH) | 686 x 171 x 145 mm (27.0 x 6.8 x 5.7 in) | | | | | |
|------------------------|---|---|--|--|--|--|--|
| | Power Supply (LxWxH) Chiller (LxWxH) | 509 x 483 x 177 mm (20.0 x 19.0 x 7 in) 699 x 483 x 411 mm (27.5 x 19.0 x 16.2 in) | | | | | |
| Weight | Optical Head | 20.4 kg (45 lbs) | | | | | |
| | Power Supply Chiller | 17.7 kg (39 lbs) 55 kg (122 lbs) | | | | | |
| Cooling | | Air-Water; Water-Water cooling option available | | | | | |
| Electrical Service | Power Supply | Single-phase: 200-240 VAC, 50/60 Hz Operating current: 5A, Max current: 10A | | | | | |
| | Chiller | Single-phase: 230 ±10% VAC, 50/60 Hz Operating current: 10A, Max current: 15A | | | | | |
| Temperature & Humidity | Operating Temperature Storage Temperature Relative Humidity | 15 to 35° C -20C to 50° C 8-80%, non-condensing | | | | | |
| Umbilical Length | | 3.65 m (12.0 ft) | | | | | |
| Control Interface | User Interface | Full featured front panel control | | | | | |
| | Serial Interface | RS-232 | | | | | |
| | Rear Connections | External beam enable, External trigger | | | | | |
| | Control Software | MS Windows-based Laser Commander™ | | | | | |

Mesa Physical Layout

All dimensions are in inches [mm]









Amplitude Laser Group Continuum I Amplitude Technologies I Amplitude Systèmes

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